

MBR2035CT THRU MBR20200CT

20.0 AMPS. Schottky
Barrier Rectifiers

Voltage Range
35 to 200 Volts
Current
20.0 Amperes

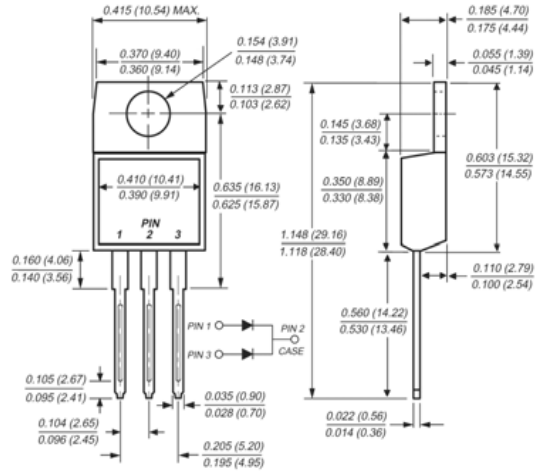
Features

- Plastic material used carries Underwriters Laboratory
- Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed:
260°C/10 seconds, 0.25"(6.35mm) from case

Mechanical Data

- Cases: JEDEC TO-220 molded plastic
- Terminals: Leads solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. - lbs. max
- Weight: 0.08 ounce, 2.24 grams

TO-220AB



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBR20 35CT	MBR20 45CT	MBR20 50CT	MBR20 60CT	MBR20 100CT	MBR20 150CT	MBR20 200CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	100	150	200	V
Maximum RMS Voltage	V_{RMS}	24	31	35	42	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	100	150	200	V
Maximum Average Forward Rectified Current at $T_C=135^\circ\text{C}$	$I_{(AV)}$	20							A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20KHz) at $T_C=135^\circ\text{C}$	I_{FRM}	20.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150							A
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1.0	0.5					1.0	A
Maximum Instantaneous Forward Voltage at (Note 2) IF=10A, $T_C=25^\circ\text{C}$ IF=10A, $T_C=125^\circ\text{C}$ IF=20A, $T_C=25^\circ\text{C}$ IF=20A, $T_C=125^\circ\text{C}$	V_F	-	0.57	0.80	0.70	0.85	0.75	0.99	V
Maximum Instantaneous Reverse Current @ $T_C=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_C=125^\circ\text{C}$	I_R	0.1	0.15	15			1.0	20	mA mA
Voltage Rate of Change, (Rated V_R)	dV/dt	10,000							V/ μs
Typical Junction Capacitance	C_j	400	320						pF
Typical Thermal Resistance Per Leg (Note 3)	$R_{\theta JC}$	1.0				2.0			$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	T_J	-65 to +150							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +175							$^\circ\text{C}$

Notes: 1. 2.0us Pulse Width, $f=1.0$ KHz

2. Pulse Test: 300us Pulse Width, 1% Duty Cycle

3. Thermal Resistance from Junction to Case Per Leg, with Heatsink Size (4"x6"x0.25") Al-Plate.

RATING AND CHARACTERISTIC CURVES MBR2035CT THRU MBR20200CT

FIG.1- FORWARD CURRENT DERATING CURVE

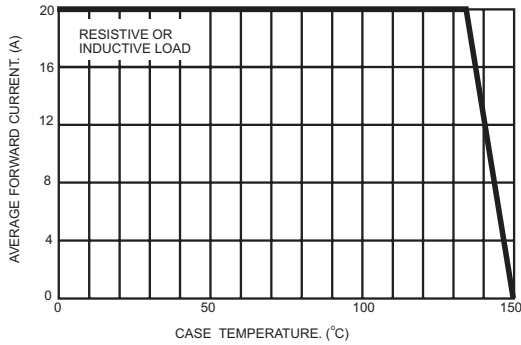


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

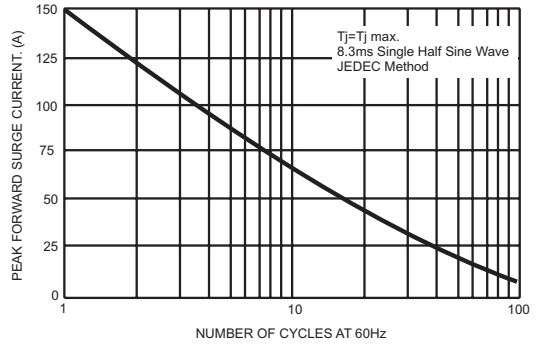


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG

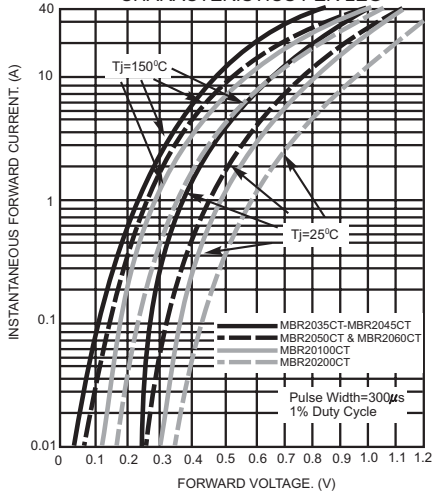


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER LEG

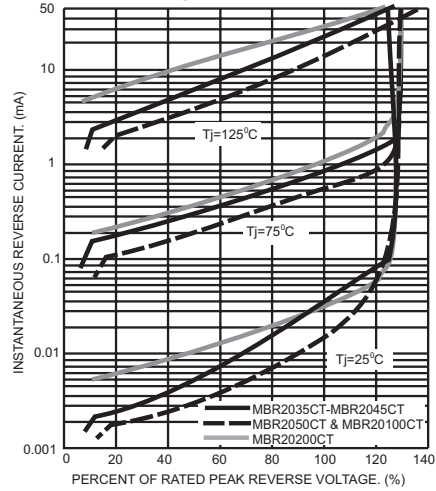


FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG

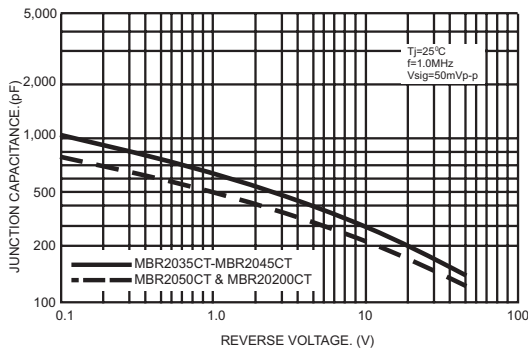


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE PER LEG

